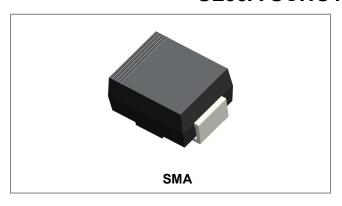




## **SL53A SCHOTTKY RECTIFIER**



# **Circuit Diagram**



## **Features**

- Schottky Barrier Chip
- Guard Ring Die Construction for Transient Protection
- High Current Capability
- Low Power Loss, High Efficiency
- High Surge Current Capability
- For Use in Low Voltage, High Frequency Inverters, Free Wheeling, and Polarity Protection Applications
- Terminals finish: 100% Pure Tin
- This is a Halogen Free device
- All SMC parts are traceable to the wafer lot
- Additional testing can be offered upon request

## **Applications**

- · Switching power supply
- Converters
- Free-Wheeling diodes
- Reverse battery protection

## **Maximum Ratings:**

Characteristics	Symbol	Condition	Max.	Units
Peak Repetitive Reverse Voltage Working Peak Reverse Voltage DC Blocking Voltage	$egin{array}{c} V_{RRM} \ V_{RWM} \ \end{array}$	-	30	V
Average Rectified Forward Current	I <sub>F (AV)</sub>	50% duty cycle @T <sub>c</sub> =75°C, rectangular wave form	5	А
Peak One Cycle Non-Repetitive Surge Current	I <sub>FSM</sub>	8.3ms, Half Sine pulse, T <sub>c</sub> = 25 °C	120	А

#### **Electrical Characteristics:**

Characteristics	Symbol	Condition	Тур.	Max.	Units
Forward Voltage Drop*	V <sub>F1</sub>	@ 5A, Pulse, T <sub>J</sub> = 25 °C	0.42	0.50	V
	V <sub>F2</sub>	@ 5A, Pulse, T <sub>J</sub> = 125℃	0.31	0.45	V
Reverse Current*	I <sub>R1</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 25 ℃	0.06	0.5	mA
	I <sub>R2</sub>	@V <sub>R</sub> = rated V <sub>R</sub> , T <sub>J</sub> = 100℃	-	20	mA
Junction Capacitance	Cj	$@V_R = 5.0 \text{ V}, \text{Tc=}25^{\circ}\text{C}$ $f_{\text{SIG}} = 1\text{MHz}$	366	500	pF

<sup>\*</sup> Pulse width < 300 µs, duty cycle < 2%

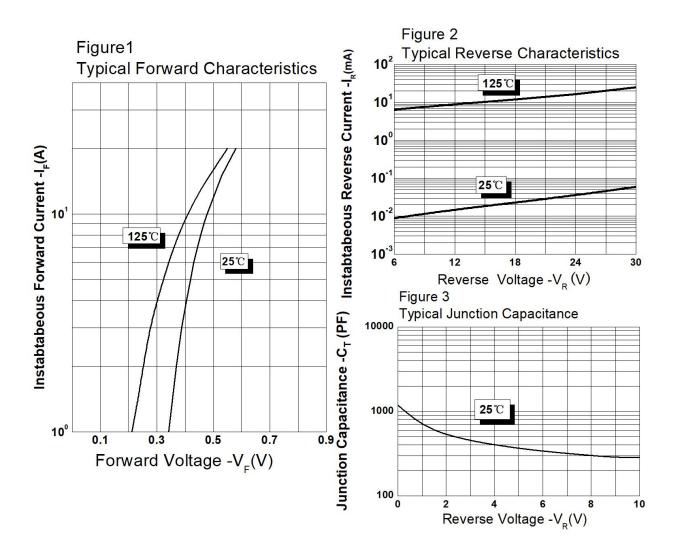




## **Thermal-Mechanical Specifications:**

Characteristics	Symbol	Condition	Specification	Units
Junction Temperature	TJ	-	-55 to +125	°C
Storage Temperature	T <sub>stg</sub>	-	-55 to +150	°C
Typical ThermalResistance Junction to Case	R <sub>0</sub> JC	-	8	°C/W
Approximate Weight	wt	-	0.06	g

## **Ratings and Characteristics Curves**



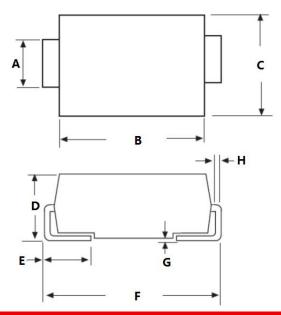
<sup>•</sup> China - Germany - Korea - Singapore - United States •

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#### **Mechanical Dimensions SMA**



SYMBOL	Millimeters		Inches		
STIVIDUL	Min.	Max.	Min.	Max.	
Α	1.25	1.65	0.049	0.065	
В	3.95	4.60	0.156	0.181	
С	2.25	2.95	0.089	0.116	
D	1.95	2.90	0.077	0.114	
Е	0.75	1.60	0.030	0.063	
F	4.80	5.60	0.189	0.220	
G	0.05	0.20	0.002	0.008	
Н	0.15	0.41	0.006	0.016	

## **Ordering Information**

Device	Package	Shipping
SL53A	SMA	5000pcs / reel
SL53ATR	SMA	5000pcs / reel

For information on tape and reel specifications, including part orientation and tape sizes, please refer to our tape and reel packaging specification.

## **Marking Diagram**



Where XXXXX is YYWWL

 SL
 = Device Type

 5
 = Forward Current (5A)

 3
 = Reverse Voltage (30V)

 A
 = Package type

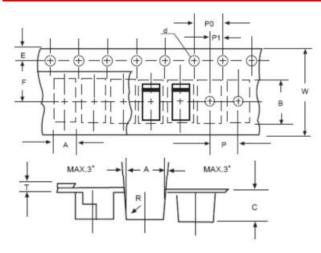
 YY
 = Year

 WW
 = Week

 L
 = Lot Number

**Cautions:** Molding resin Epoxy resin UL:94V-0

# **Carrier Tape Specification SMA**



SYMBOL	Millimeters		
STIVIBUL	Min.	Max.	
Α	2.97	3.17	
В	5.70	5.90	
С	2.32	2.52	
d	1.40	1.60	
E	1.40	1.60	
F	5.60	5.70	
Р	3.90	4.10	
P0	3.90	4.10	
P1	1.90	2.10	
Т	0.25	0.35	
W	11.80	12.20	

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